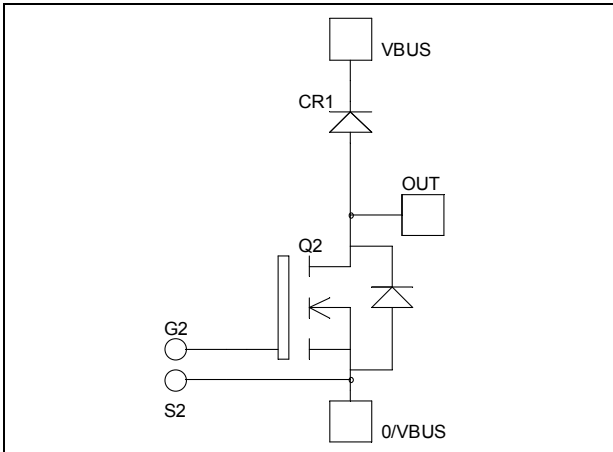


## Boost chopper MOSFET Power Module

**$V_{DSS} = 1000V$**   
 **$R_{DSon} = 90m\Omega$  typ @  $T_j = 25^\circ C$**   
 **$I_D = 78A$  @  $T_c = 25^\circ C$**


**Application**

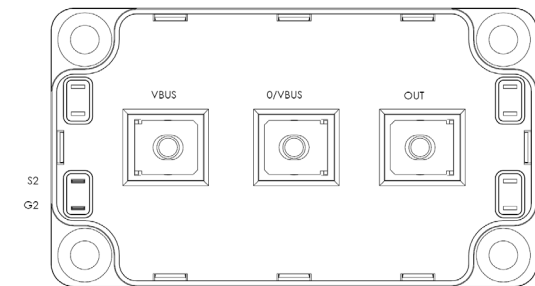
- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

**Features**

- Power MOS 7<sup>®</sup> MOSFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

**Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant


**Absolute maximum ratings**

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	1000	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	78
		$T_c = 80^\circ C$	59
$I_{DM}$	Pulsed Drain current	312	A
$V_{GS}$	Gate - Source Voltage	$\pm 30$	
$R_{DSon}$	Drain - Source ON Resistance	105	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	1250
$I_{AR}$	Avalanche current (repetitive and non repetitive)	25	A
$E_{AR}$	Repetitive Avalanche Energy	50	$mJ$
$E_{AS}$	Single Pulse Avalanche Energy	3000	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$			400	$\mu\text{A}$
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 25^\circ\text{C}$		2000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$		90	105	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10\text{mA}$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 250$	$\text{nA}$

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1\text{MHz}$		20.7		$\text{nF}$
$C_{oss}$	Output Capacitance			3.5		
$C_{rss}$	Reverse Transfer Capacitance			0.64		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 500V$ $I_D = 78A$		744		$\text{nC}$
$Q_{gs}$	Gate – Source Charge			96		
$Q_{gd}$	Gate – Drain Charge			488		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ 125°C</b> $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 78A$ $R_G = 1.2\Omega$		18		$\text{ns}$
$T_r$	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			155		
$T_f$	Fall Time			40		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 78A, R_G = 1.2\Omega$		3.6		$\text{mJ}$
$E_{off}$	Turn-off Switching Energy			2.5		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 78A, R_G = 1.2\Omega$		5.7		$\text{mJ}$
$E_{off}$	Turn-off Switching Energy			3.1		

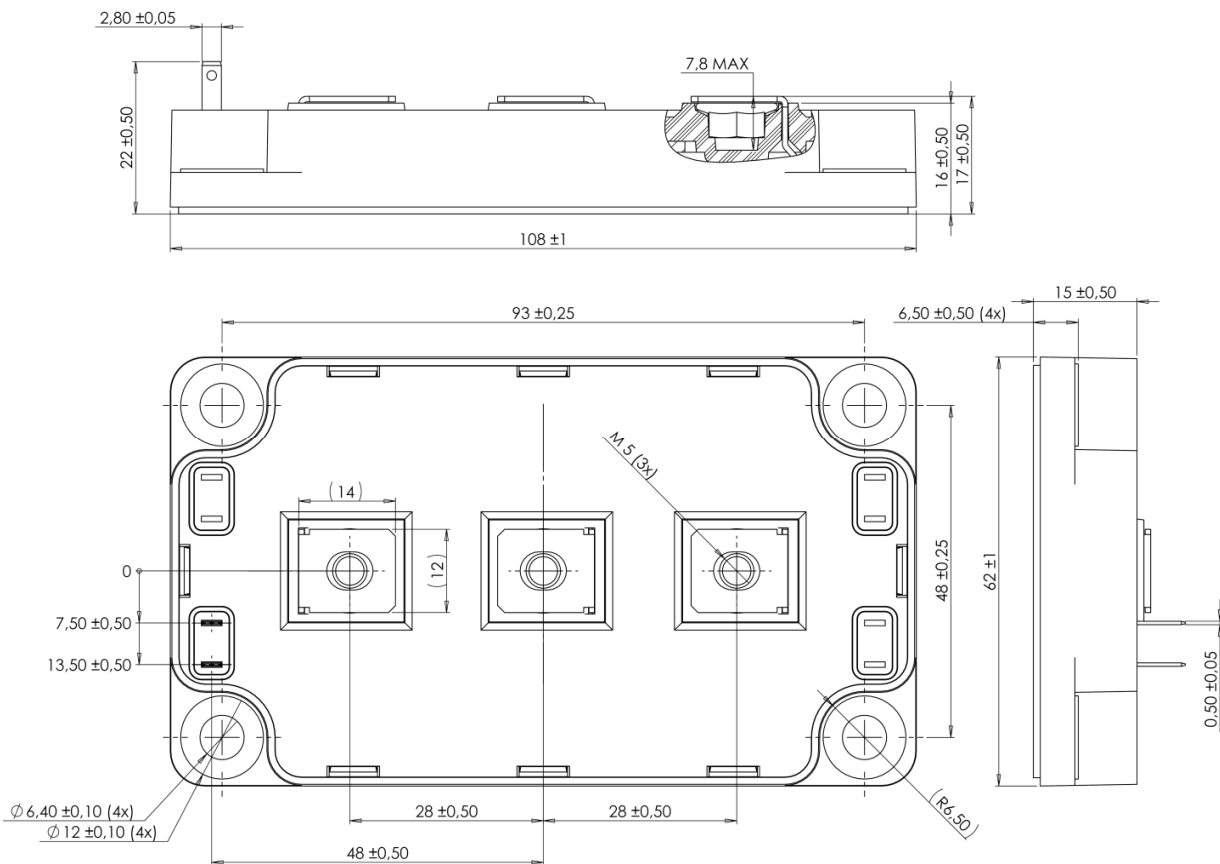
**Chopper diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		1000			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1000V$	$T_j = 25^\circ\text{C}$		250	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$		500	
$I_F$	DC Forward Current	$T_c = 70^\circ\text{C}$		100		A
$V_F$	Diode Forward Voltage	$I_F = 100A$		1.9	2.5	V
		$I_F = 200A$		2.2		
		$I_F = 100A$	$T_j = 125^\circ\text{C}$		1.7	
$t_{rr}$	Reverse Recovery Time	$I_F = 100A$ $V_R = 670V$ $di/dt = 200A/\mu\text{s}$	$T_j = 25^\circ\text{C}$		300	$\text{ns}$
			$T_j = 125^\circ\text{C}$		360	
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$		800	$\text{nC}$
			$T_j = 125^\circ\text{C}$		4050	

## Thermal and package characteristics

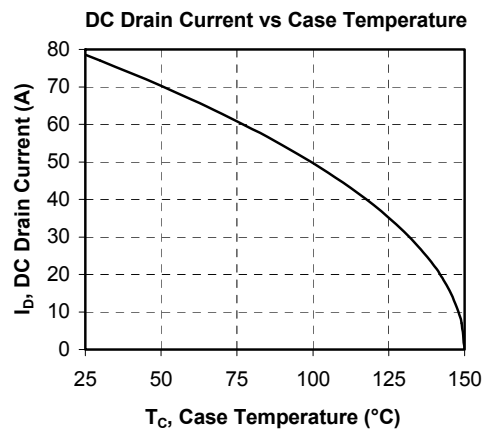
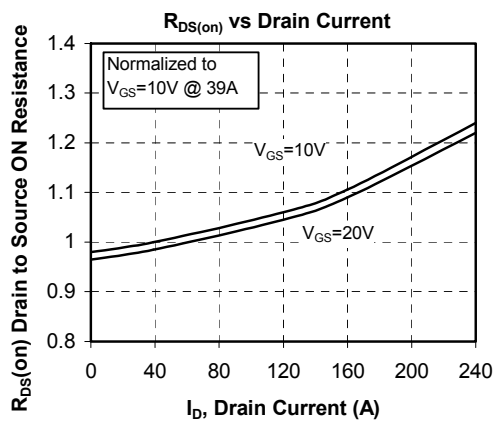
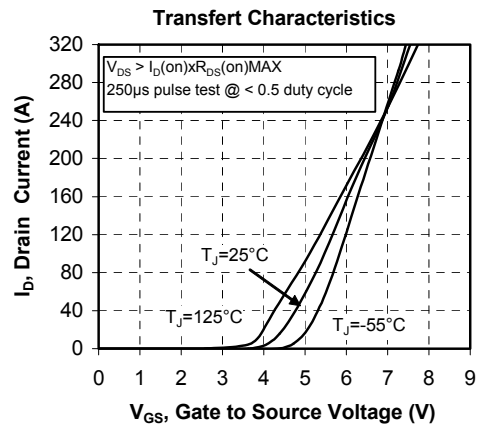
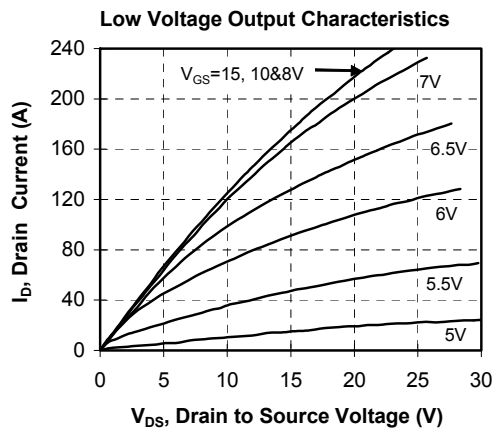
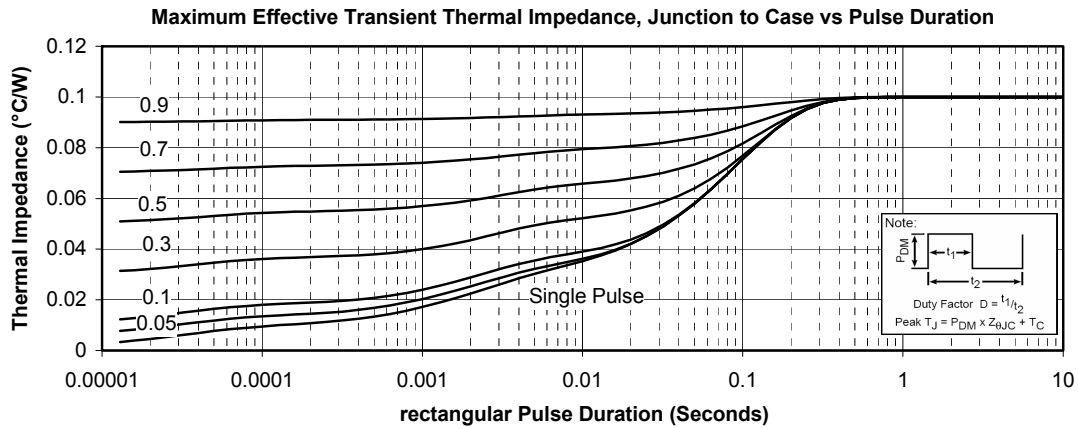
Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance	Transistor			0.1	°C/W
		Diode			0.55	
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz		4000			V
T <sub>J</sub>	Operating junction temperature range		-40		150	°C
T <sub>STG</sub>	Storage Temperature Range		-40		125	
T <sub>C</sub>	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight				300	g

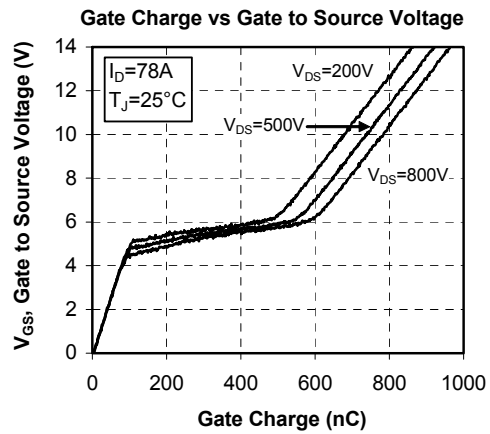
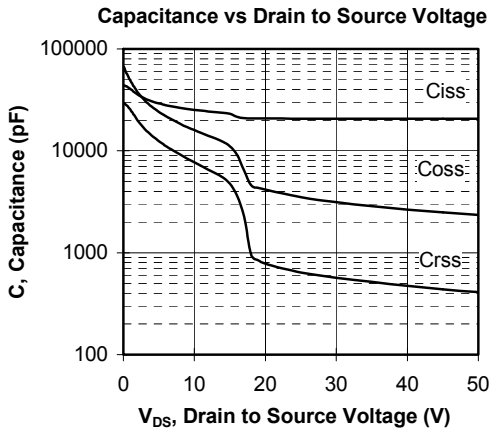
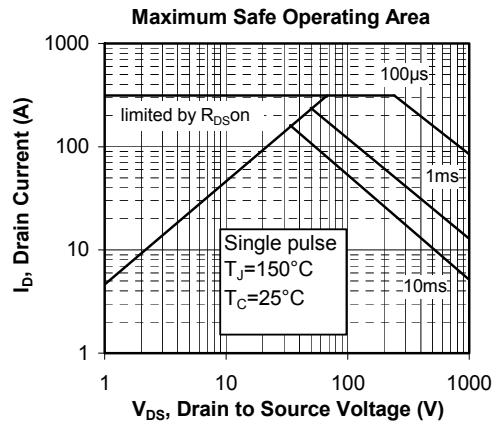
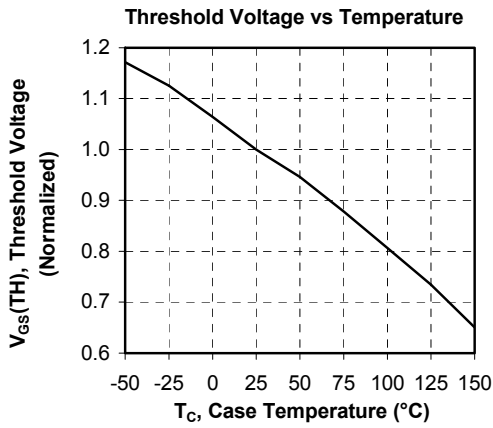
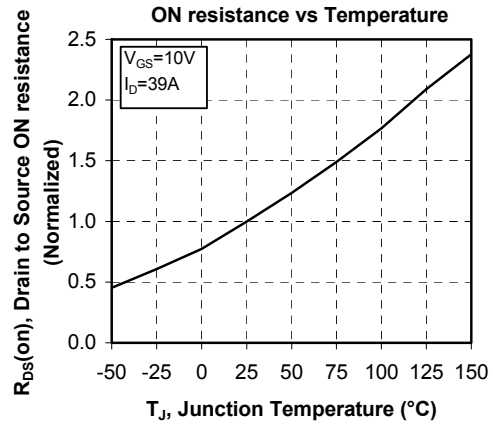
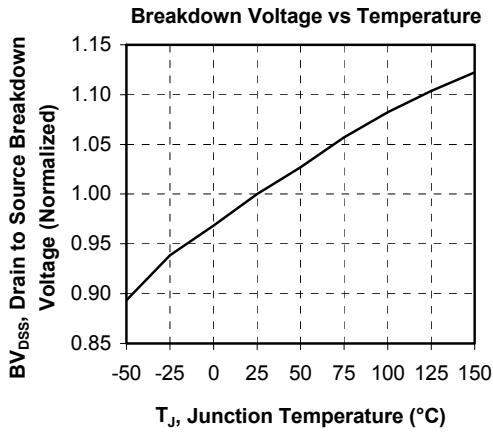
## SP6 Package outline (dimensions in mm)

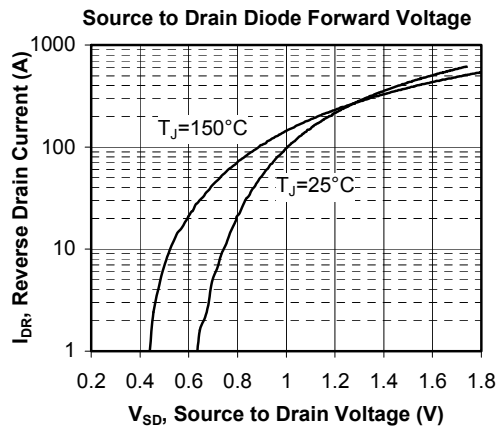
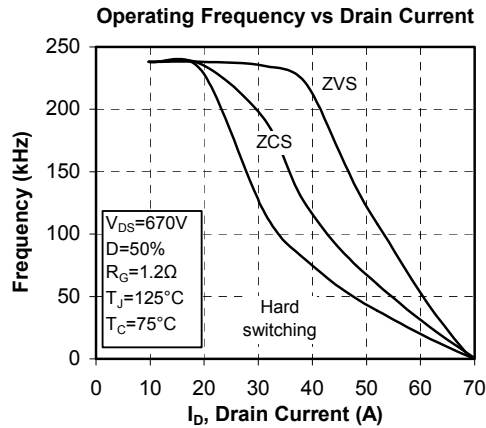
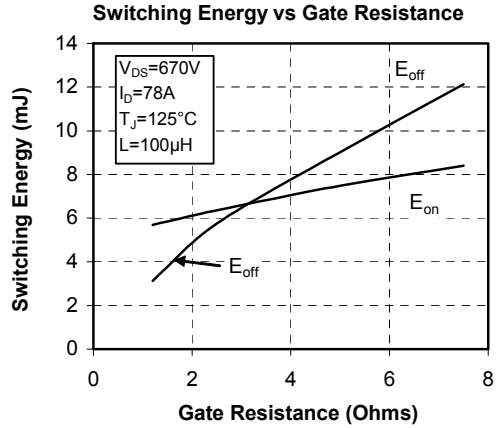
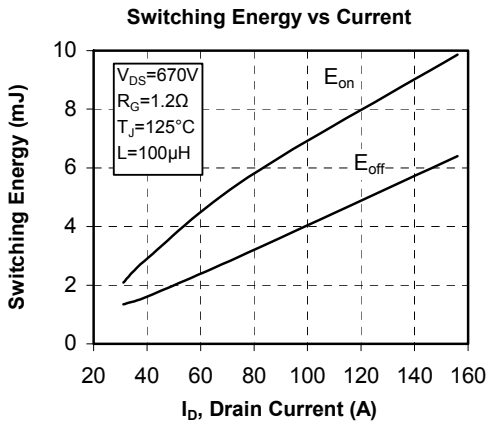
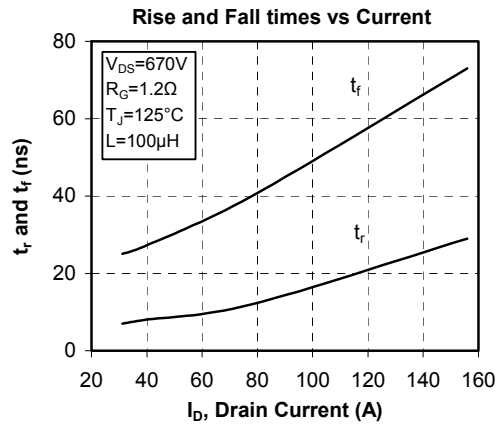
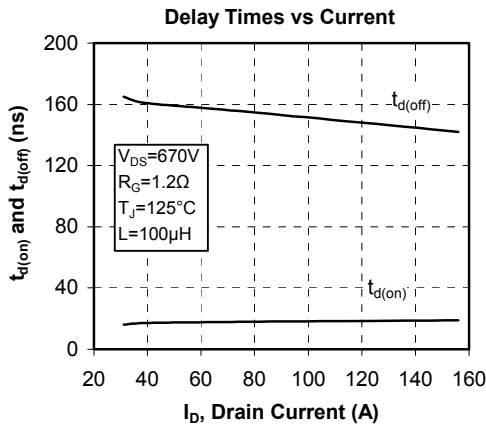


V

See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

**Typical Performance Curve**






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